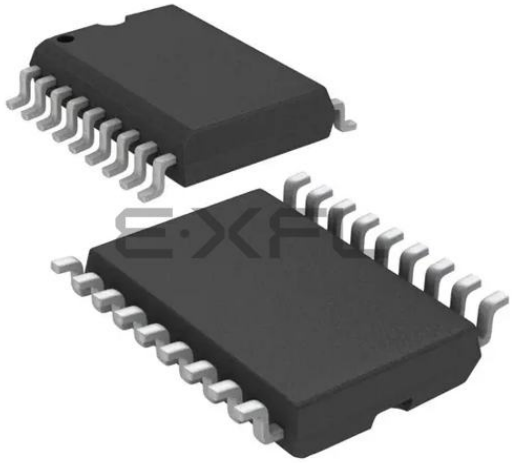


Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	13
Program Memory Size	896B (512 x 14)
Program Memory Type	FLASH
EEPROM Size	64 x 8
RAM Size	36 x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 6V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	18-SOIC (0.295", 7.50mm Width)
Supplier Device Package	18-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16lf83t-04-so

2.0 PIC16F8X DEVICE VARIETIES

A variety of frequency ranges and packaging options are available. Depending on application and production requirements the proper device option can be selected using the information in this section. When placing orders, please use the "PIC16F8X Product Identification System" at the back of this data sheet to specify the correct part number.

There are four device "types" as indicated in the device number.

1. **F**, as in PIC16**F**84. These devices have Flash program memory and operate over the standard voltage range.
2. **LF**, as in PIC16**LF**84. These devices have Flash program memory and operate over an extended voltage range.
3. **CR**, as in PIC16**CR**83. These devices have ROM program memory and operate over the standard voltage range.
4. **LCR**, as in PIC16**LCR**84. These devices have ROM program memory and operate over an extended voltage range.

When discussing memory maps and other architectural features, the use of **F** and **CR** also implies the **LF** and **LCR** versions.

2.1 Flash Devices

These devices are offered in the lower cost plastic package, even though the device can be erased and reprogrammed. This allows the same device to be used for prototype development and pilot programs as well as production.

A further advantage of the electrically-erasable Flash version is that it can be erased and reprogrammed in-circuit, or by device programmers, such as Microchip's PICSTART® Plus or PRO MATE® II programmers.

2.2 Quick-Turnaround-Production (QTP) Devices

Microchip offers a QTP Programming Service for factory production orders. This service is made available for users who choose not to program a medium to high quantity of units and whose code patterns have stabilized. The devices have all Flash locations and configuration options already programmed by the factory. Certain code and prototype verification procedures do apply before production shipments are available.

For information on submitting a QTP code, please contact your Microchip Regional Sales Office.

2.3 Serialized Quick-Turnaround-Production (SQTP^{SM}) Devices

Microchip offers the unique programming service where a few user-defined locations in each device are programmed with different serial numbers. The serial numbers may be random, pseudo-random or sequential.

Serial programming allows each device to have a unique number which can serve as an entry-code, password or ID number.

For information on submitting a SQTP code, please contact your Microchip Regional Sales Office.

2.4 ROM Devices

Some of Microchip's devices have a corresponding device where the program memory is a ROM. These devices give a cost savings over Microchip's traditional user programmed devices (EPROM, EEPROM).

ROM devices (PIC16CR8X) do not allow serialization information in the program memory space. The user may program this information into the Data EEPROM.

For information on submitting a ROM code, please contact your Microchip Regional Sales Office.

NOTES:

4.2.2.2 OPTION_REG REGISTER

The OPTION_REG register is a readable and writable register which contains various control bits to configure the TMR0/WDT prescaler, the external INT interrupt, TMR0, and the weak pull-ups on PORTB.

Note:	When the prescaler is assigned to the WDT (PSA = '1'), TMR0 has a 1:1 prescaler assignment.

FIGURE 4-1: OPTION_REG REGISTER (ADDRESS 81h)

R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1	R/W-1
$\overline{\text{RBPU}}$	INTEDG	T0CS	T0SE	PSA	PS2	PS1	PS0
bit7							bit0

R = Readable bit
W = Writable bit
U = Unimplemented bit, read as '0'
- n = Value at POR reset

bit 7: **$\overline{\text{RBPU}}$**: PORTB Pull-up Enable bit
1 = PORTB pull-ups are disabled
0 = PORTB pull-ups are enabled (by individual port latch values)

bit 6: **INTEDG**: Interrupt Edge Select bit
1 = Interrupt on rising edge of RB0/INT pin
0 = Interrupt on falling edge of RB0/INT pin

bit 5: **T0CS**: TMR0 Clock Source Select bit
1 = Transition on RA4/T0CKI pin
0 = Internal instruction cycle clock (CLKOUT)

bit 4: **T0SE**: TMR0 Source Edge Select bit
1 = Increment on high-to-low transition on RA4/T0CKI pin
0 = Increment on low-to-high transition on RA4/T0CKI pin

bit 3: **PSA**: Prescaler Assignment bit
1 = Prescaler assigned to the WDT
0 = Prescaler assigned to TMR0

bit 2-0: **PS2:PS0**: Prescaler Rate Select bits

Bit Value	TMR0 Rate	WDT Rate
000	1 : 2	1 : 1
001	1 : 4	1 : 2
010	1 : 8	1 : 4
011	1 : 16	1 : 8
100	1 : 32	1 : 16
101	1 : 64	1 : 32
110	1 : 128	1 : 64
111	1 : 256	1 : 128

5.3 I/O Programming Considerations

5.3.1 BI-DIRECTIONAL I/O PORTS

Any instruction which writes, operates internally as a read followed by a write operation. The BCF and BSF instructions, for example, read the register into the CPU, execute the bit operation and write the result back to the register. Caution must be used when these instructions are applied to a port with both inputs and outputs defined. For example, a BSF operation on bit5 of PORTB will cause all eight bits of PORTB to be read into the CPU. Then the BSF operation takes place on bit5 and PORTB is written to the output latches. If another bit of PORTB is used as a bi-directional I/O pin (i.e., bit0) and it is defined as an input at this time, the input signal present on the pin itself would be read into the CPU and rewritten to the data latch of this particular pin, overwriting the previous content. As long as the pin stays in the input mode, no problem occurs. However, if bit0 is switched into output mode later on, the content of the data latch is unknown.

Reading the port register, reads the values of the port pins. Writing to the port register writes the value to the port latch. When using read-modify-write instructions (i.e., BCF, BSF, etc.) on a port, the value of the port pins is read, the desired operation is done to this value, and this value is then written to the port latch.

A pin actively outputting a Low or High should not be driven from external devices at the same time in order to change the level on this pin ("wired-or", "wired-and"). The resulting high output current may damage the chip.

5.3.2 SUCCESSIVE OPERATIONS ON I/O PORTS

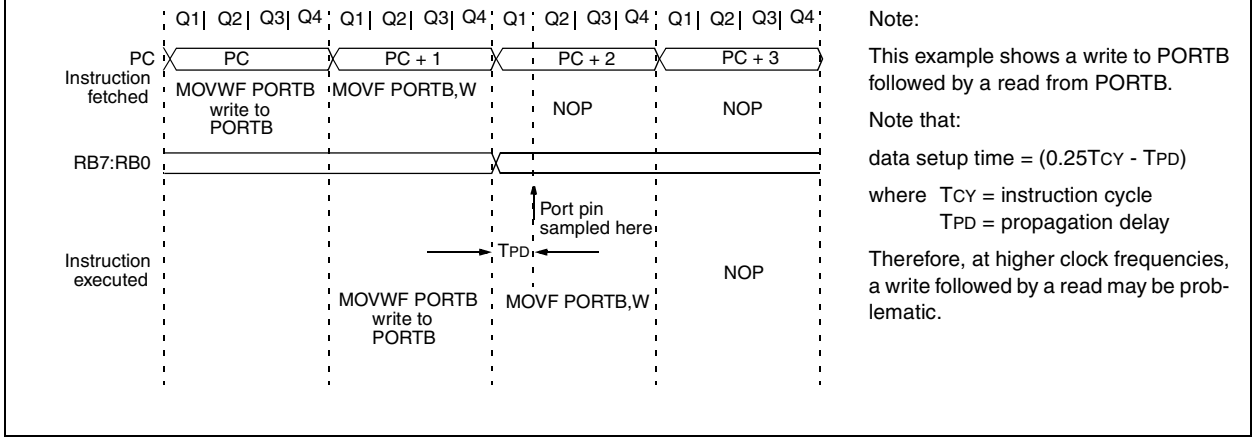
The actual write to an I/O port happens at the end of an instruction cycle, whereas for reading, the data must be valid at the beginning of the instruction cycle (Figure 5-5). Therefore, care must be exercised if a write followed by a read operation is carried out on the same I/O port. The sequence of instructions should be such that the pin voltage stabilizes (load dependent) before the next instruction which causes that file to be read into the CPU is executed. Otherwise, the previous state of that pin may be read into the CPU rather than the new state. When in doubt, it is better to separate these instructions with a NOP or another instruction not accessing this I/O port.

Example 5-1 shows the effect of two sequential read-modify-write instructions (e.g., BCF, BSF, etc.) on an I/O port.

EXAMPLE 5-1: READ-MODIFY-WRITE INSTRUCTIONS ON AN I/O PORT

```
;Initial PORT settings: PORTB<7:4> Inputs
;                       PORTB<3:0> Outputs
;PORTB<7:6> have external pull-ups and are
;not connected to other circuitry
;
;                     PORT latch  PORT pins
;                     ----------  ---------
  BCF PORTB, 7      ; 01pp ppp    11pp ppp
  BCF PORTB, 6      ; 10pp ppp    11pp ppp
  BSF STATUS, RP0   ;
  BCF TRISB, 7      ; 10pp ppp    11pp ppp
  BCF TRISB, 6      ; 10pp ppp    10pp ppp
;
;Note that the user may have expected the
;pin values to be 00pp ppp. The 2nd BCF
;caused RB7 to be latched as the pin value
;(high).
```

FIGURE 5-5: SUCCESSIVE I/O OPERATION



Note:

This example shows a write to PORTB followed by a read from PORTB.

Note that:

data setup time = (0.25TCY - TPD)

where TCY = instruction cycle
TPD = propagation delay

Therefore, at higher clock frequencies, a write followed by a read may be problematic.

6.0 TIMER0 MODULE AND TMR0 REGISTER

The Timer0 module timer/counter has the following features:

- 8-bit timer/counter
- Readable and writable
- 8-bit software programmable prescaler
- Internal or external clock select
- Interrupt on overflow from FFh to 00h
- Edge select for external clock

Timer mode is selected by clearing the T0CS bit (OPTION_REG<5>). In timer mode, the Timer0 module (Figure 6-1) will increment every instruction cycle (without prescaler). If the TMR0 register is written, the increment is inhibited for the following two cycles (Figure 6-2 and Figure 6-3). The user can work around this by writing an adjusted value to the TMR0 register.

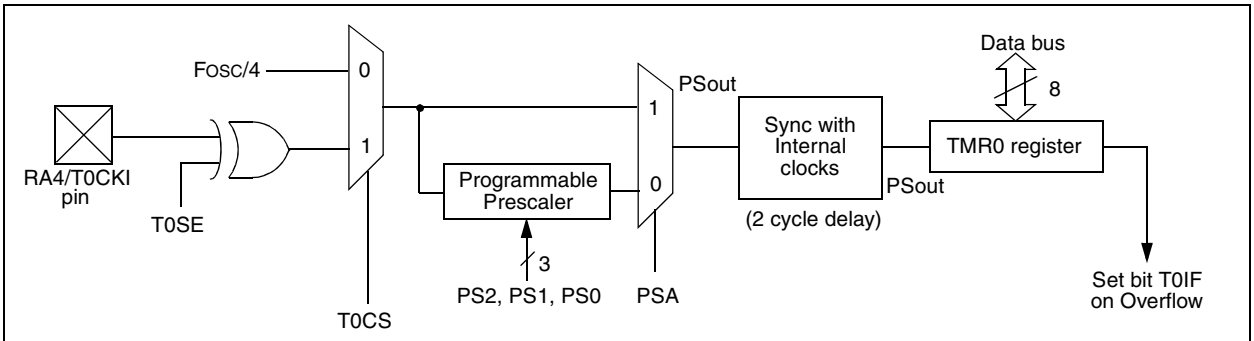
Counter mode is selected by setting the T0CS bit (OPTION_REG<5>). In this mode TMR0 will increment either on every rising or falling edge of pin RA4/T0CKI. The incrementing edge is determined by the T0 source edge select bit, T0SE (OPTION_REG<4>). Clearing bit T0SE selects the rising edge. Restrictions on the external clock input are discussed in detail in Section 6.2.

The prescaler is shared between the Timer0 Module and the Watchdog Timer. The prescaler assignment is controlled, in software, by control bit PSA (OPTION_REG<3>). Clearing bit PSA will assign the prescaler to the Timer0 Module. The prescaler is not readable or writable. When the prescaler (Section 6.3) is assigned to the Timer0 Module, the prescale value (1:2, 1:4, ..., 1:256) is software selectable.

6.1 TMR0 Interrupt

The TMR0 interrupt is generated when the TMR0 register overflows from FFh to 00h. This overflow sets the T0IF bit (INTCON<2>). The interrupt can be masked by clearing enable bit T0IE (INTCON<5>). The T0IF bit must be cleared in software by the Timer0 Module interrupt service routine before re-enabling this interrupt. The TMR0 interrupt (Figure 6-4) cannot wake the processor from SLEEP since the timer is shut off during SLEEP.

FIGURE 6-1: TMR0 BLOCK DIAGRAM



Note 1: Bits T0CS, T0SE, PS2, PS1, PS0 and PSA are located in the OPTION_REG register.
2: The prescaler is shared with the Watchdog Timer (Figure 6-6)

FIGURE 6-2: TMR0 TIMING: INTERNAL CLOCK/NO PRESCALER

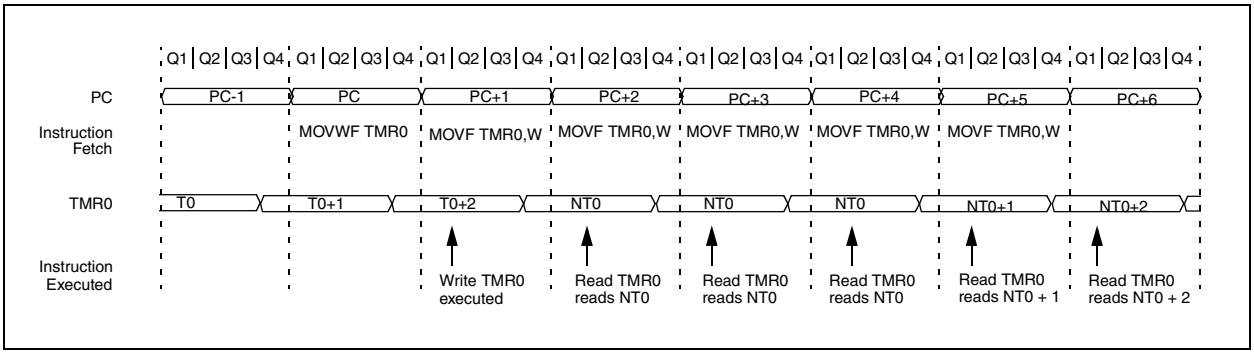
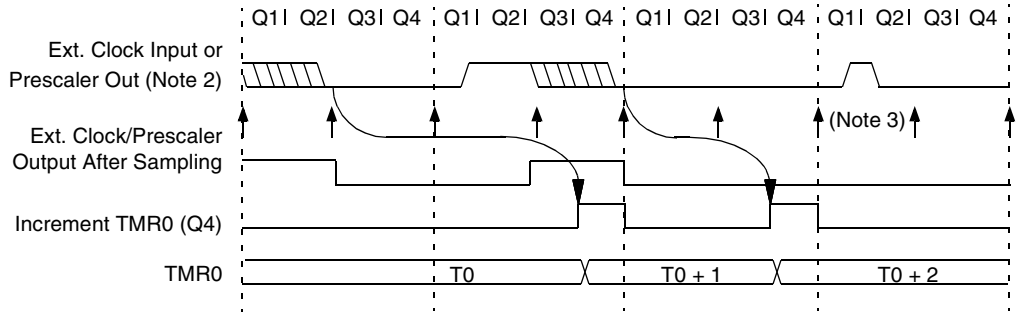
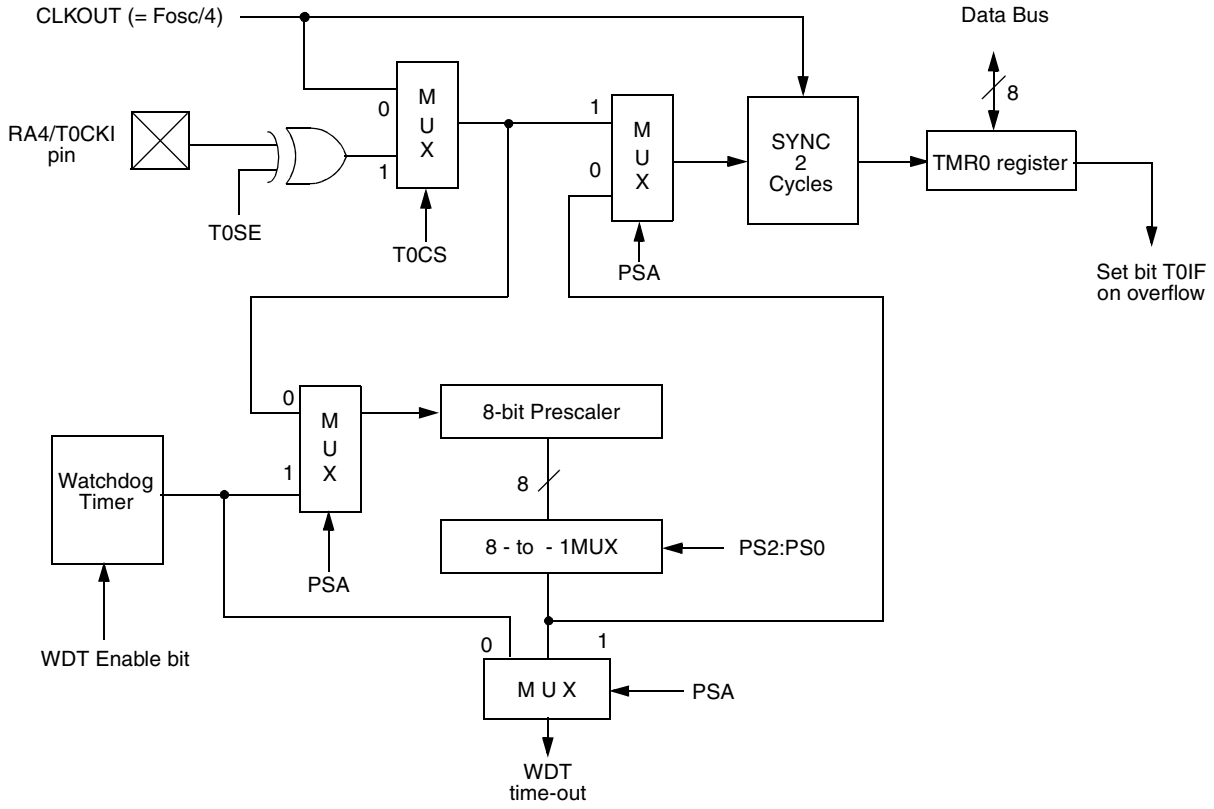


FIGURE 6-5: TIMER0 TIMING WITH EXTERNAL CLOCK



Note 1: Delay from clock input change to TMR0 increment is 3Tosc to 7Tosc. (Duration of Q = Tosc). Therefore, the error in measuring the interval between two edges on TMR0 input = ± 4Tosc max.
2: External clock if no prescaler selected, Prescaler output otherwise.
3: The arrows ↑ indicate where sampling occurs. A small clock pulse may be missed by sampling.

FIGURE 6-6: BLOCK DIAGRAM OF THE TMR0/WDT PRESCALER



Note: T0CS, T0SE, PSA, PS2:PS0 are bits in the OPTION_REG register.

NOTES:

FIGURE 8-2: CONFIGURATION WORD - PIC16F83 AND PIC16F84

R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u	R/P-u
CP	CP	CP	CP	CP	CP	CP	CP	CP	CP	$\overline{\text{PWRTE}}$	WDTE	FOSC1	FOSC0

bit13 bit0

R = Readable bit
P = Programmable bit
- n = Value at POR reset
u = unchanged

bit 13:4 **CP**: Code Protection bit
1 = Code protection off
0 = All memory is code protected

bit 3 **$\overline{\text{PWRTE}}$**: Power-up Timer Enable bit
1 = Power-up timer is disabled
0 = Power-up timer is enabled

bit 2 **WDTE**: Watchdog Timer Enable bit
1 = WDT enabled
0 = WDT disabled

bit 1:0 **FOSC1:FOSC0**: Oscillator Selection bits
11 = RC oscillator
10 = HS oscillator
01 = XT oscillator
00 = LP oscillator

8.2 Oscillator Configurations

8.2.1 OSCILLATOR TYPES

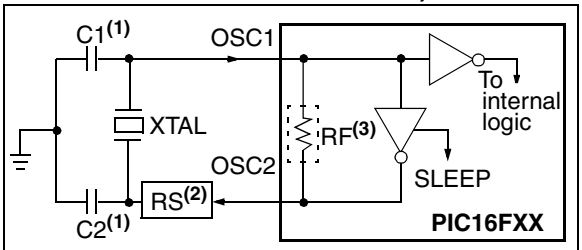
The PIC16F8X can be operated in four different oscillator modes. The user can program two configuration bits (FOSC1 and FOSC0) to select one of these four modes:

- LP Low Power Crystal
- XT Crystal/Resonator
- HS High Speed Crystal/Resonator
- RC Resistor/Capacitor

8.2.2 CRYSTAL OSCILLATOR / CERAMIC RESONATORS

In XT, LP or HS modes a crystal or ceramic resonator is connected to the OSC1/CLKIN and OSC2/CLKOUT pins to establish oscillation (Figure 8-3).

FIGURE 8-3: CRYSTAL/CERAMIC RESONATOR OPERATION (HS, XT OR LP OSC CONFIGURATION)



Note1: See Table 8-1 for recommended values of C1 and C2.
2: A series resistor (RS) may be required for AT strip cut crystals.
3: RF varies with the crystal chosen.

The PIC16F8X oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT, LP or HS modes, the device can have an external clock source to drive the OSC1/CLKIN pin (Figure 8-4).

FIGURE 8-10: TIME-OUT SEQUENCE ON POWER-UP (MCLR NOT TIED TO VDD): CASE 1

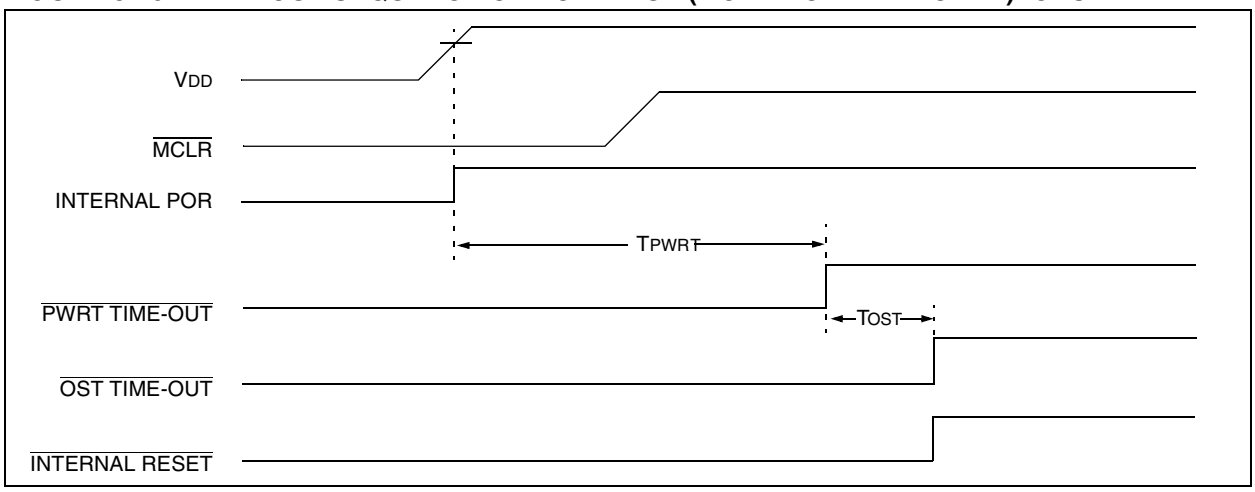
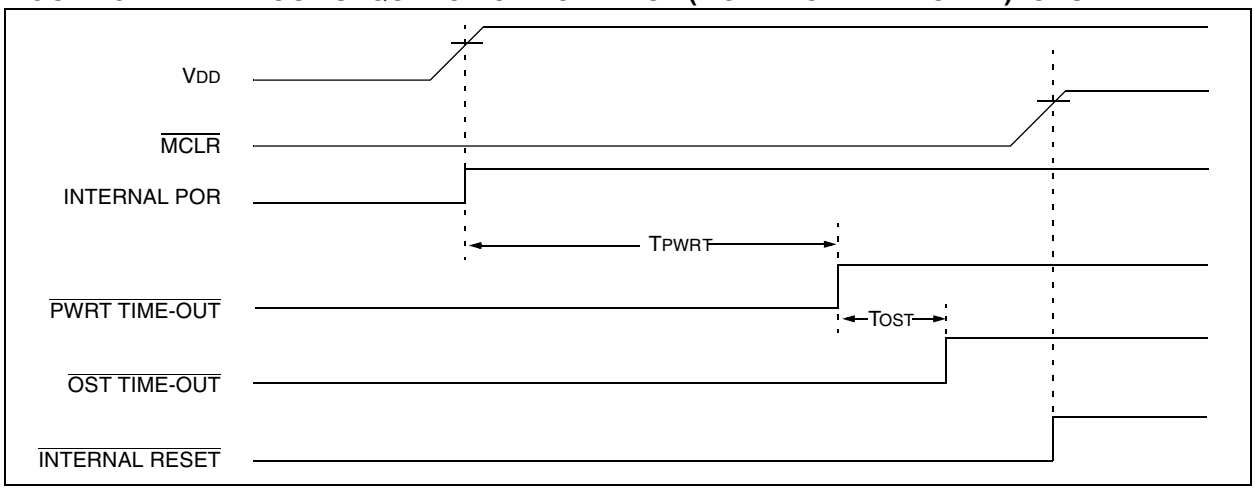


FIGURE 8-11: TIME-OUT SEQUENCE ON POWER-UP (MCLR NOT TIED TO VDD): CASE 2



8.7 Time-out Sequence and Power-down Status Bits ($\overline{TO}$/$\overline{PD}$)

On power-up (Figure 8-10, Figure 8-11, Figure 8-12 and Figure 8-13) the time-out sequence is as follows: First PWRT time-out is invoked after a POR has expired. Then the OST is activated. The total time-out will vary based on oscillator configuration and PWRTE configuration bit status. For example, in RC mode with the PWRT disabled, there will be no time-out at all.

TABLE 8-5 TIME-OUT IN VARIOUS SITUATIONS

Oscillator Configuration	Power-up		Wake-up from SLEEP
	PWRT Enabled	PWRT Disabled	
XT, HS, LP	72 ms + 1024TOSC	1024TOSC	1024TOSC
RC	72 ms	—	—

Since the time-outs occur from the POR reset pulse, if $\overline{MCLR}$ is kept low long enough, the time-outs will expire. Then bringing $\overline{MCLR}$ high, execution will begin immediately (Figure 8-10). This is useful for testing purposes or to synchronize more than one PIC16F8X device when operating in parallel.

Table 8-6 shows the significance of the $\overline{TO}$ and $\overline{PD}$ bits. Table 8-3 lists the reset conditions for some special registers, while Table 8-4 lists the reset conditions for all the registers.

TABLE 8-6 STATUS BITS AND THEIR SIGNIFICANCE

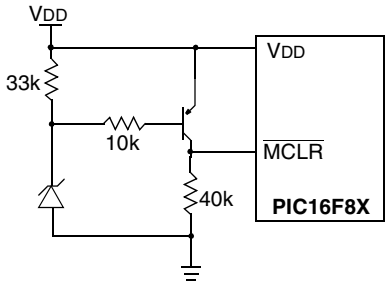
$\overline{TO}$	$\overline{PD}$	Condition
1	1	Power-on Reset
0	x	Illegal, $\overline{TO}$ is set on $\overline{POR}$
x	0	Illegal, $\overline{PD}$ is set on $\overline{POR}$
0	1	WDT Reset (during normal operation)
0	0	WDT Wake-up
1	1	$\overline{MCLR}$ Reset during normal operation
1	0	$\overline{MCLR}$ Reset during SLEEP or interrupt wake-up from SLEEP

8.8 Reset on Brown-Out

A brown-out is a condition where device power (VDD) dips below its minimum value, but not to zero, and then recovers. The device should be reset in the event of a brown-out.

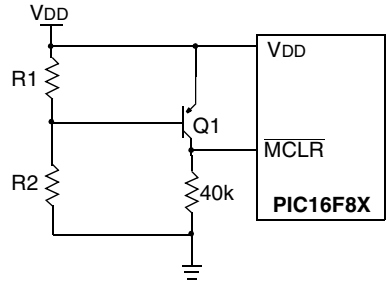
To reset a PIC16F8X device when a brown-out occurs, external brown-out protection circuits may be built, as shown in Figure 8-14 and Figure 8-15.

FIGURE 8-14: BROWN-OUT PROTECTION CIRCUIT 1



This circuit will activate reset when VDD goes below (Vz + 0.7V) where Vz = Zener voltage.

FIGURE 8-15: BROWN-OUT PROTECTION CIRCUIT 2



This brown-out circuit is less expensive, although less accurate. Transistor Q1 turns off when VDD is below a certain level such that:

$$V_{DD} \bullet \frac{R1}{R1 + R2} = 0.7V$$

8.11 Watchdog Timer (WDT)

The Watchdog Timer is a free running on-chip RC oscillator which does not require any external components. This RC oscillator is separate from the RC oscillator of the OSC1/CLKIN pin. That means that the WDT will run even if the clock on the OSC1/CLKIN and OSC2/CLKOUT pins of the device has been stopped, for example, by execution of a SLEEP instruction. During normal operation a WDT time-out generates a device RESET. If the device is in SLEEP mode, a WDT Wake-up causes the device to wake-up and continue with normal operation. The WDT can be permanently disabled by programming configuration bit WDTE as a '0' (Section 8.1).

8.11.1 WDT PERIOD

The WDT has a nominal time-out period of 18 ms, (with no prescaler). The time-out periods vary with temperature, VDD and process variations from part to part (see DC specs). If longer time-out periods are desired, a prescaler with a division ratio of up to 1:128 can be assigned to the WDT under software control by writing to the OPTION_REG register. Thus, time-out periods up to 2.3 seconds can be realized.

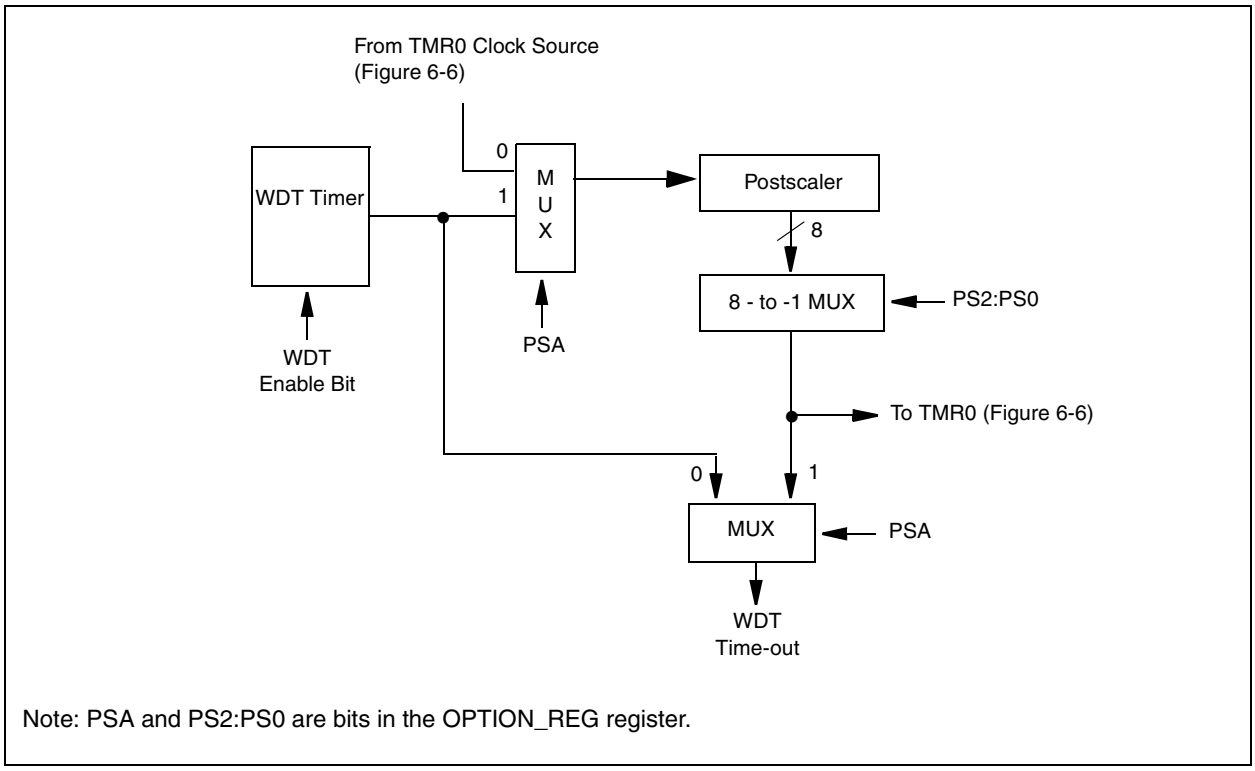
The CLRWDT and SLEEP instructions clear the WDT and the postscaler (if assigned to the WDT) and prevent it from timing out and generating a device RESET condition.

The $\overline{TO}$ bit in the STATUS register will be cleared upon a WDT time-out.

8.11.2 WDT PROGRAMMING CONSIDERATIONS

It should also be taken into account that under worst case conditions (VDD = Min., Temperature = Max., max. WDT prescaler) it may take several seconds before a WDT time-out occurs.

FIGURE 8-18: WATCHDOG TIMER BLOCK DIAGRAM



Note: PSA and PS2:PS0 are bits in the OPTION_REG register.

TABLE 8-7 SUMMARY OF REGISTERS ASSOCIATED WITH THE WATCHDOG TIMER

Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on Power-on Reset	Value on all other resets
2007h	Config. bits	(2)	(2)	(2)	(2)	PWRTE(1)	WDTE	FOSC1	FOSC0	(2)	
81h	OPTION_ REG	$\overline{RBPU}$	INTEDG	T0CS	T0SE	PSA	PS2	PS1	PS0	1111 1111	1111 1111

Legend: x = unknown. Shaded cells are not used by the WDT.
Note 1: See Figure 8-1 and Figure 8-2 for operation of the PWRTE bit.
2: See Figure 8-1, Figure 8-2 and Section 8.13 for operation of the Code and Data protection bits.

8.12 Power-down Mode (SLEEP)

A device may be powered down (SLEEP) and later powered up (Wake-up from SLEEP).

8.12.1 SLEEP

The Power-down mode is entered by executing the SLEEP instruction.

If enabled, the Watchdog Timer is cleared (but keeps running), the $\overline{PD}$ bit (STATUS<3>) is cleared, the $\overline{TO}$ bit (STATUS<4>) is set, and the oscillator driver is turned off. The I/O ports maintain the status they had before the SLEEP instruction was executed (driving high, low, or hi-impedance).

For the lowest current consumption in SLEEP mode, place all I/O pins at either at VDD or VSS, with no external circuitry drawing current from the I/O pins, and disable external clocks. I/O pins that are hi-impedance inputs should be pulled high or low externally to avoid switching currents caused by floating inputs. The T0CKI input should also be at VDD or VSS. The contribution from on-chip pull-ups on PORTB should be considered.

The $\overline{MCLR}$ pin must be at a logic high level (VIHMC).

It should be noted that a RESET generated by a WDT time-out does not drive the $\overline{MCLR}$ pin low.

8.12.2 WAKE-UP FROM SLEEP

The device can wake-up from SLEEP through one of the following events:

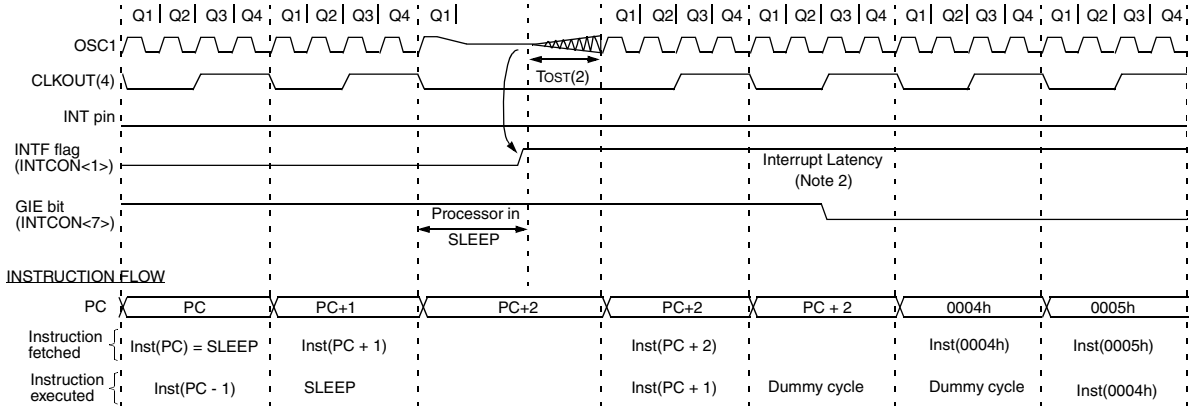
1. External reset input on $\overline{MCLR}$ pin.
2. WDT Wake-up (if WDT was enabled).
3. Interrupt from RB0/INT pin, RB port change, or data EEPROM write complete.

Peripherals cannot generate interrupts during SLEEP, since no on-chip Q clocks are present.

The first event ($\overline{MCLR}$ reset) will cause a device reset. The two latter events are considered a continuation of program execution. The $\overline{TO}$ and $\overline{PD}$ bits can be used to determine the cause of a device reset. The $\overline{PD}$ bit, which is set on power-up, is cleared when SLEEP is invoked. The $\overline{TO}$ bit is cleared if a WDT time-out occurred (and caused wake-up).

While the SLEEP instruction is being executed, the next instruction (PC + 1) is pre-fetched. For the device to wake-up through an interrupt event, the corresponding interrupt enable bit must be set (enabled). Wake-up occurs regardless of the state of the GIE bit. If the GIE bit is clear (disabled), the device continues execution at the instruction after the SLEEP instruction. If the GIE bit is set (enabled), the device executes the instruction after the SLEEP instruction and then branches to the interrupt address (0004h). In cases where the execution of the instruction following SLEEP is not desirable, the user should have a NOP after the SLEEP instruction.

FIGURE 8-19: WAKE-UP FROM SLEEP THROUGH INTERRUPT



Note 1: XT, HS or LP oscillator mode assumed.
2: TOST = 1024TOSC (drawing not to scale) This delay will not be there for RC osc mode.
3: GIE = '1' assumed. In this case after wake- up, the processor jumps to the interrupt routine. If GIE = '0', execution will continue in-line.
4: CLKOUT is not available in these osc modes, but shown here for timing reference.

10.4 DC CHARACTERISTICS: PIC16F84, PIC16F83 (Commercial, Industrial) PIC16LF84, PIC16F83 (Commercial, Industrial)

DC Characteristics All Pins Except Power Supply Pins			Standard Operating Conditions (unless otherwise stated) Operating temperature 0°C ≤ TA ≤ +70°C (commercial) -40°C ≤ TA ≤ +85°C (industrial) Operating voltage VDD range as described in DC spec Section 10.1 and Section 10.2.				
Parameter No.	**Sym**	**Characteristic**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
		Capacitive Loading Specs on Output Pins					
D100	COSC2	OSC2 pin	—	—	15	pF	In XT, HS and LP modes when external clock is used to drive OSC1.
D101	CIO	All I/O pins and OSC2 (RC mode)	—	—	50	pF	
		Data EEPROM Memory					
D120	ED	Endurance	1M	10M	—	E/W	25°C at 5V
D121	VDRW	VDD for read/write	VMIN	—	6.0	V	VMIN = Minimum operating voltage
D122	TDEW	Erase/Write cycle time	—	10	20*	ms	
		Program Flash Memory					
D130	EP	Endurance	100	1000	—	E/W	
D131	VPR	VDD for read	VMIN	—	6.0	V	VMIN = Minimum operating voltage
D132	VPEW	VDD for erase/write	4.5	—	5.5	V	
D133	TPEW	Erase/Write cycle time	—	10	—	ms	

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

11.2 DC CHARACTERISTICS: PIC16LCR84, PIC16LCR83 (Commercial, Industrial)

DC Characteristics Power Supply Pins			Standard Operating Conditions (unless otherwise stated) Operating temperature 0°C ≤ TA ≤ +70°C (commercial) -40°C ≤ TA ≤ +85°C (industrial)				
Parameter No.	**Sym**	**Characteristic**	**Min**	**Typ†**	**Max**	**Units**	**Conditions**
D001	VDD	Supply Voltage	2.0	—	6.0	V	XT, RC, and LP osc configuration
D002	VDR	RAM Data Retention Voltage(1)	1.5*	—	—	V	Device in SLEEP mode
D003	VPOR	VDD start voltage to ensure internal Power-on Reset signal	—	VSS	—	V	See section on Power-on Reset for details
D004	SVDD	VDD rise rate to ensure internal Power-on Reset signal	0.05*	—	—	V/ms	See section on Power-on Reset for details
	IDD	Supply Current(2)					RC and XT osc configuration(4)
D010			—	1	4	mA	FOSC = 2.0 MHz, VDD = 5.5V
D010A			—	7.3	10	mA	FOSC = 2.0 MHz, VDD = 5.5V (During EEPROM programming)
							LP osc configuration
D014			—	15	45	µA	FOSC = 32 kHz, VDD = 2.0V, WDT disabled
D020	IPD	Power-down Current(3)	—	3.0	16	µA	VDD = 2.0V, WDT enabled, industrial
D021			—	0.4	5.0	µA	VDD = 2.0V, WDT disabled, commercial
D021A			—	0.4	6.0	µA	VDD = 2.0V, WDT disabled, industrial

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.
The test conditions for all IDD measurements in active operation mode are:
OSC1=external square wave, from rail to rail; all I/O pins tristated, pulled to VDD, T0CKI = VDD, $\overline{MCLR}$ = VDD; WDT enabled/disabled as specified.

3: The power down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD and VSS.

4: For RC osc configuration, current through Rext is not included. The current through the resistor can be estimated by the formula IR = VDD/2Rext (mA) with Rext in kOhm.

11.5 Timing Diagrams and Specifications

FIGURE 11-3: EXTERNAL CLOCK TIMING

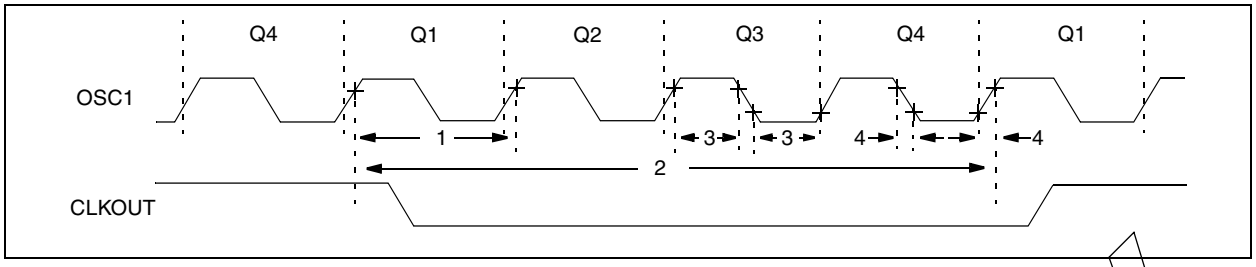


TABLE 11-3 EXTERNAL CLOCK TIMING REQUIREMENTS

Parameter No.	Sym	Characteristic	Min	Typ†	Max	Units	Conditions	
	FOSC	**External CLKIN Frequency(1)**	DC	—	2	MHz	XT, RC osc	PIC16LCR8X-04
			DC	—	4	MHz	XT, RC osc	PIC16CR8X-04
			DC	—	10	MHz	HS osc	PIC16CR8X-10
			DC	—	200	kHz	LP osc	PIC16LCR8X-04
		Oscillator Frequency(1)	DC	—	2	MHz	RC osc	PIC16LCR8X-04
			DC	—	4	MHz	RC osc	PIC16CR8X-04
			0.1	—	2	MHz	XT osc	PIC16LCR8X-04
			0.1	—	4	MHz	XT osc	PIC16CR8X-04
			1.0	—	10	MHz	HS osc	PIC16CR8X-10
			DC	—	200	kHz	LP osc	PIC16LCR8X-04
1	TOSC	**External CLKIN Period(1)**	500	—	—	ns	XT, RC osc	PIC16LCR8X-04
			250	—	—	ns	XT, RC osc	PIC16CR8X-04
			100	—	—	ns	HS osc	PIC16CR8X-10
			5.0	—	—	µs	LP osc	PIC16LCR8X-04
		Oscillator Period(1)	500	—	—	ns	RC osc	PIC16LCR8X-04
			250	—	—	ns	RC osc	PIC16CR8X-04
			500	—	10,000	ns	XT osc	PIC16LCR8X-04
			250	—	10,000	ns	XT osc	PIC16CR8X-04
			100	—	1,000	ns	HS osc	PIC16CR8X-10
			5.0	—	—	µs	LP osc	PIC16LCR8X-04
2	TCY	**Instruction Cycle Time(1)**	0.4	4/Fosc	DC	µs		
3	TosL, TosH	**Clock in (OSC1) High or Low Time**	60 *	—	—	ns	XT osc	PIC16LCR8X-04
			50 *	—	—	ns	XT osc	PIC16CR8X-04
			2.0 *	—	—	µs	LP osc	PIC16LCR8X-04
			35 *	—	—	ns	HS osc	PIC16CR8X-10
4	TosR, TosF	**Clock in (OSC1) Rise or Fall Time**	25 *	—	—	ns	XT osc	PIC16CR8X-04
			50 *	—	—	ns	LP osc	PIC16LCR8X-04
			15 *	—	—	ns	HS osc	PIC16CR8X-10

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Instruction cycle period (TCY) equals four times the input oscillator time base period. All specified values are based on characterization data for that particular oscillator type under standard operating conditions with the device executing code. Exceeding these specified limits may result in an unstable oscillator operation and/or higher than expected current consumption. All devices are tested to operate at "min." values with an external clock applied to the OSC1 pin.
When an external clock input is used, the "Max." cycle time limit is "DC" (no clock) for all devices.

12.0 DC & AC CHARACTERISTICS GRAPHS/TABLES

The graphs and tables provided in this section are for **design guidance** and are **not tested or guaranteed**.

In some graphs or tables, the data presented are **outside specified operating range** (i.e., outside specified VDD range). This is for **information only** and devices are guaranteed to operate properly only within the specified range.

The data presented in this section is a **statistical summary** of data collected on units from different lots over a period of time and matrix samples. 'Typical' represents the mean of the distribution at 25°C, while 'max' or 'min' represents (mean + 3σ) and (mean - 3σ) respectively, where σ is standard deviation.

FIGURE 12-1: TYPICAL RC OSCILLATOR FREQUENCY vs. TEMPERATURE

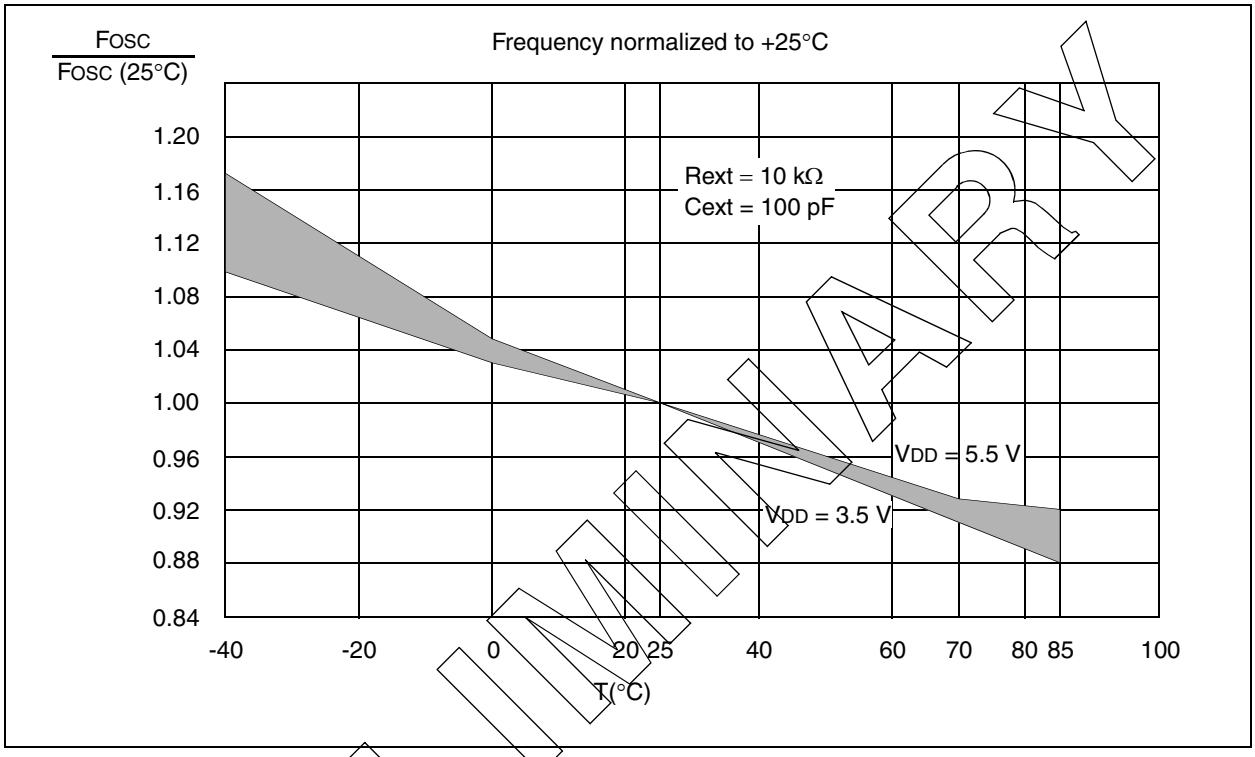


TABLE 12-1 RC OSCILLATOR FREQUENCIES*

Cext	Rext	Average Fosc @ 5V, 25°C	
			Part to Part Variation
20 pF	5 k	4.61 MHz	± 25%
	10 k	2.66 MHz	± 24%
	100 k	311 kHz	± 39%
100 pF	5 k	1.34 MHz	± 21%
	10 k	756 kHz	± 18%
	100 k	82.8 kHz	± 28%
300 pF	5 k	428 kHz	± 13%
	10 k	243 kHz	± 13%
	100 k	26.2 kHz	± 23%

* Measured on DIP packages. The percentage variation indicated here is part-to-part variation due to normal process distribution. The variation indicated is ±3 standard deviation from average value for full VDD range.

FIGURE 12-15: TRANSCONDUCTANCE (gm) OF LP OSCILLATOR vs. VDD

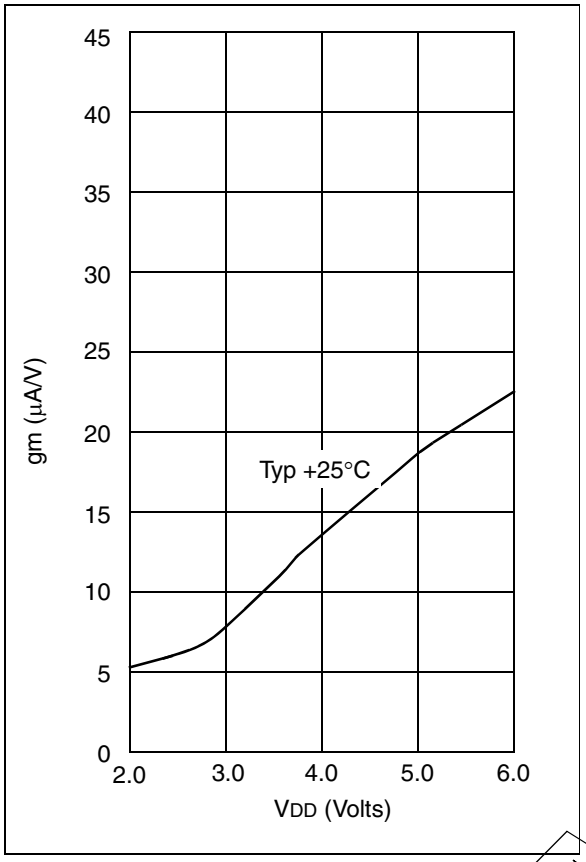
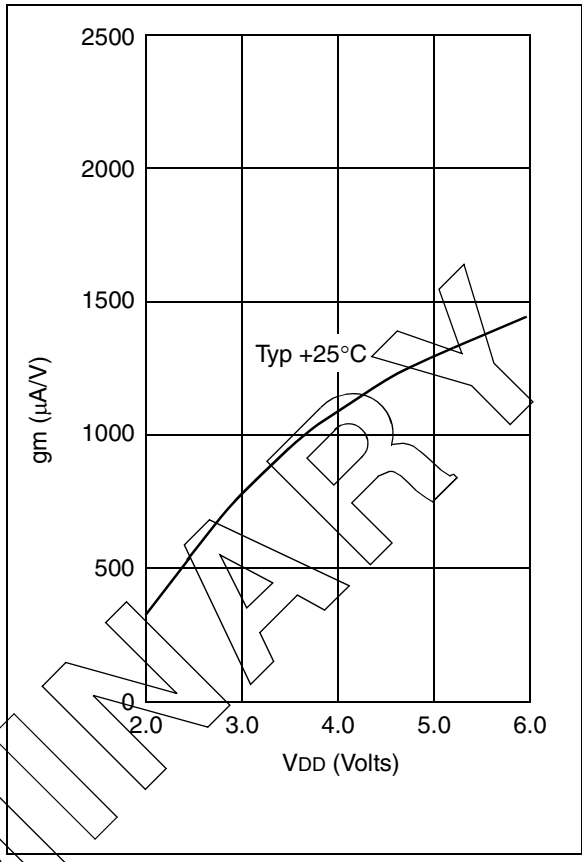


FIGURE 12-16: TRANSCONDUCTANCE (gm) OF XT OSCILLATOR vs. VDD



NOTES:

NOTES: